

HD74LS107A

Dual J-K Negative-edge-triggered Flip-Flops (with Clear)

REJ03D0425-0300 Rev.3.00 Jul.13.2005

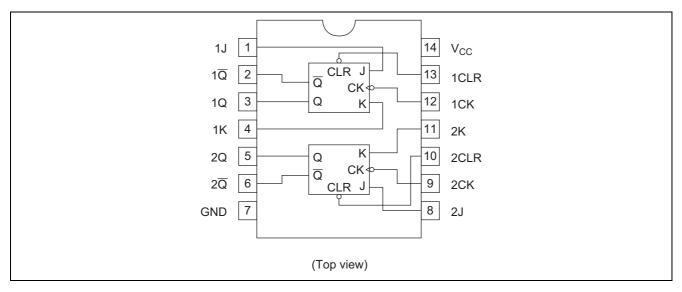
Features

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LS107AP	DILP-14 pin	PRDP0014AB-B (DP-14AV)	Р	_
HD74LS107AFPEL	SOP-14 pin (JEITA)	PRSP0014DF-B (FP-14DAV)	FP	EL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

Pin Arrangement



Function Table

	Inp	Outputs			
Clear	Clock	J	K	Q	Q
L	X	X	Х	L	Н
Н	\	L	L	Qo	\overline{Q}_O
Н	\	Н	L	Н	L
Н	\	L	Н	L	Н
Н	<u> </u>	Н	Н	Toggle	
Н	Н	X	Х	Qo	\overline{Q}_O

Notes: H; high level, L; low level, X; irrelevant

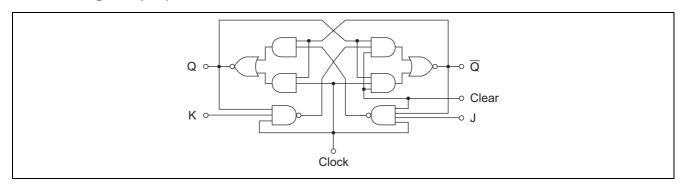
↓; transition from high to low level

Q; level of Q before the indicated steady-state input conditions were established.

 \overline{Q} ; complement of Q_0 or level of \overline{Q} before the indicated steady-state input conditions were established.

Toggle; each output changes to the complement of its previous level on each active transition indicated by ↓.

Block Diagram (1/2)



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage	V _{CC}	7	V
Input voltage	V _{IN}	7	V
Power dissipation	P _T	400	mW
Storage temperature	Tstg	-65 to +150	°C

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

Recommended Operating Conditions

Item		Symbol	Min	Тур	Max	Unit
Supply voltage	Supply voltage		4.75	5.00	5.25	V
Output ourrent	0.4		_	_	-400	μΑ
Output current		I _{OL}	_	_	8	mA
Operating temperature		Topr	-20	25	75	°C
Clock frequency		f _{clock}	0	_	30	MHz
Dulas width	Clock High	4	20	_	_	ns
Pulse width	Clear Low	- t _w	25	_	_	ns
Cotup time	"H" Data	4	20↓	_	_	ns
Setup time	"L" Data	- t _{su}	20↓	_	_	ns
Hold time		t _h	0↓	_	_	ns

Electrical Characteristics

 $(Ta = -20 \text{ to } +75 \text{ }^{\circ}\text{C})$

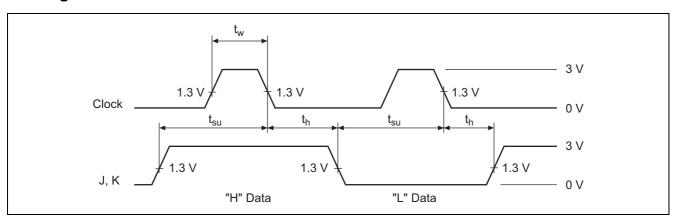
Item		Symbol	min.	typ.*	max.	Unit	Condition	
Input voltage		V _{IH}	2.0	_	_	V		
		V _{IL}	_	_	0.8	V		
		V _{OH}	2.7	_	_	V	$V_{CC} = 4.75 \text{ V}, V_{IH} = 2 \text{ V}, V_{IL} = 0.8 \text{ V}, \\ I_{OH} = -400 \mu\text{A}$	
Output volta	age		_	_	0.5	V	$I_{OL} = 8 \text{ mA}$ $V_{CC} = 4.75 \text{ V}, V_{IH} = 2 \text{ V},$	
		V _{OL}	_	_	0.4	V	I _{OL} = 4 mA V _{IL} = 0.8 V	
	J, K		_	_	20			
	Clear	I _{IH}	_	_	60	μΑ	$V_{CC} = 5.25 \text{ V}, V_{I} = 2.7 \text{ V}$	
	Clock		_	_	80			
lam.ut	J, K		_	_	-0.4		V _{CC} = 5.25 V, V _i = 0.4 V	
Input	Clear	I _{IL}	_	_	-0.8	mA		
Current	Clock		_	_	-0.8			
	J, K		_	_	0.1			
	Clear	l _i	_	_	0.3	mA	$V_{CC} = 5.25 \text{ V}, V_{I} = 7 \text{ V}$	
	Clock]	_	_	0.4			
Short-circui current	t output	los	-20	_	-100	mA	V _{CC} = 5.25 V	
Supply curr	ent**	Icc	_	4	6	mA	V _{CC} = 5.25 V	
Input clamp voltage		V _{Ik}	_	_	-1.5	V	$V_{CC} = 4.75 \text{ V}, I_{IN} = -18 \text{ mA}$	

Switching Characteristics

$$(V_{CC} = 5 \text{ V}, \text{ Ta} = 25^{\circ}\text{C})$$

Item	Symbol	Inputs	Outputs	min.	typ.	max.	Unit	Condition
Maximum clock frequency	f_{max}			30	45	_	MHz	0 45 -5
Propagation delay time	t _{PLH}	Clear	Q, \overline{Q}	_	15	20	ns	$C_L = 15 \text{ pF},$ $R_L = 2 \text{ k}\Omega$
	t _{PHL}	Clock	Q, Q		15	20	ns	11 - 2 1/22

Timing Definition

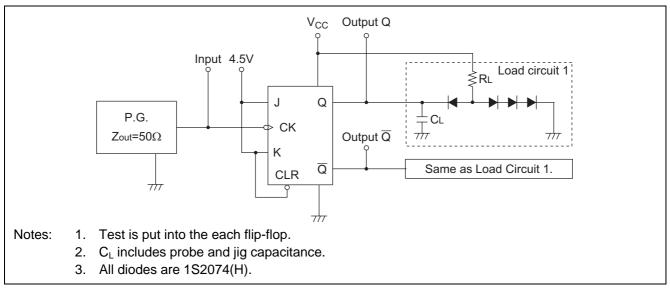


Notes: ${}^*V_{CC} = 5 \text{ V}$, Ta = 25°C *W With all outputs open, I_{CC} is measured with the Q and \overline{Q} outputs high in turn. At the tires of measurement, the clock input is grounded.

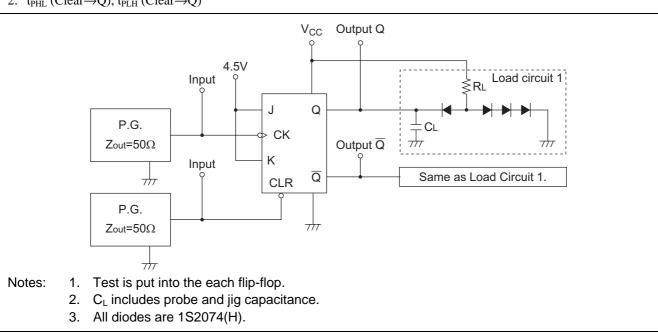
Testing Method

Test Circuit

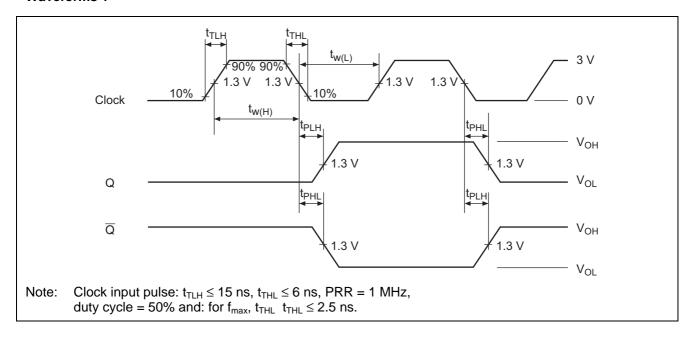
1. f_{max} , t_{PLH} , t_{PHL} , (Clock \rightarrow Q, \overline{Q})



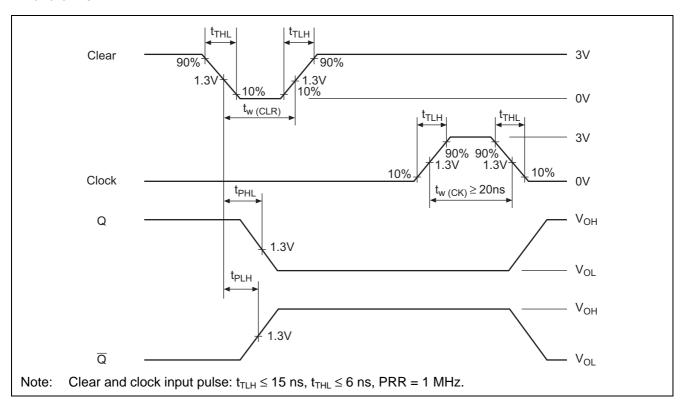
2. t_{PHL} (Clear \rightarrow Q), t_{PLH} (Clear \rightarrow \overline{Q})



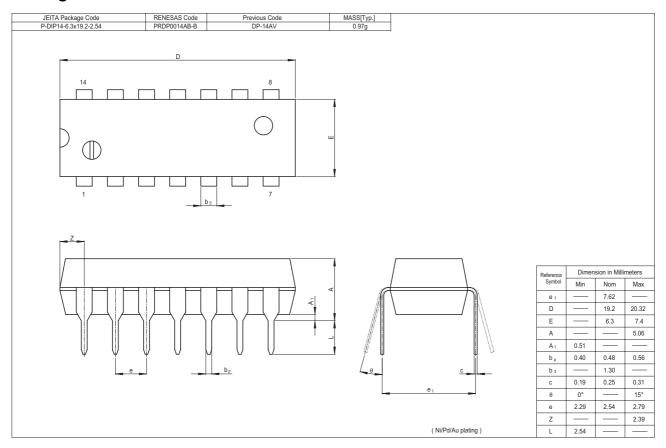
Waveforms 1

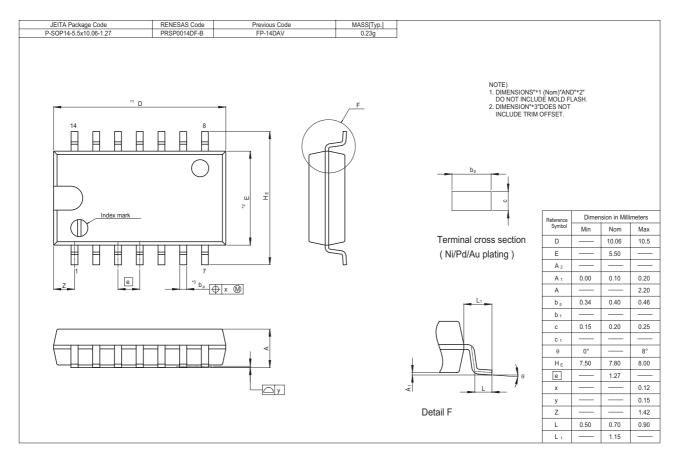


Waveforms 2



Package Dimensions





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